

NEME

FAYYAZ

Ahmad

ID

13460

subject Basic

electronic

①

Q10 Explain how the transformer turns ratio effects the rectified output voltage of full wave rectifier?

Answer: If the transformer's turns ratio is 1 the peak value of the rectified output voltage equals half the peak value of the primary input voltage less the barrier potential. This is because half of the primary voltage appears across each half of the secondary winding V_s equals to the input peak so a step up transformer with a turns ratio of $n=2$ must be used

$$V_{out} = (V_{s0}/2) - 0.7V \text{ \% } 3Dsec.$$

②

① Compare the center-tapped rectifier and Bridge rectifier?

① Center-tapped rectifier and Bridge rectifier:

The main difference b/w a center Tapped a Bridge rectifier is that one uses center tapped Transformer while another do not require a center tapped transformer. Both these types are full wave rectifier but their method of converting AC input into DC is different by employing different number ~~number~~ diodes. In center tapped full wave rectifier two diodes are used whereas four diodes are used in bridge rectifier.

③
① List advantages and disadvantages of RC filter and LC filter?

RC filters, advantages:

- Ans: 1) Reduced size and weight
2) increased reliability and improved performance
3) in large quantities, the cost of an RC is less than its passive counterpart.

② Disadvantages

- 1) limited bandwidth of active devices
- 2) required power supplies
- 3) increased sensitivity to variations in ~~voice~~ circuit parameter.

② LL Filter Advantages

- 1) The choke input (LL) filter has a high output DC voltage
- 2) it has no loading effect on the rectifier
- 3) This diode does not have to carry surge currents

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• Disadvantages:

- (1) it cannot be used together with half wave rectifier
- (2) Due to inductor it produces the audible noise
- (3) it is not useful for very low load currents
- (4) There is loss of power in the series inductor due to its DC resistance.

Q2

a. What would be an advantage of a $50\ \Omega$ voltage source compared to a $600\ \Omega$ voltage source?

Answer:

For the $50\ \text{ohm}$ voltage source, maximum power transfer will occur when the load has a resistance $50\ \text{ohms}$. Similarly, $600\ \text{ohms}$ is required for max power transfer into an impedance that presents itself as $600\ \text{ohms}$. You need to maintain the integrity of the impedance at all points if you are to avoid reflections down the line and damaging the output PA. So, if you had an antenna rated at $50\ \text{ohms}$ connected to a $50\ \text{ohms}$ feed then all things being equal SWR etc you be better with $50\ \text{ohms}$ source. Some configurations of antenna may be "see" as presenting an impedance of say $580\ \text{ohms}$ in which case the $600\ \text{ohm}$ may be the closest and best alternative.

B) Which approximation does the technician normally use when performing initial troubleshooting procedures? Why?

Answer:

Experienced technicians often use a type of statistical approach for troubleshooting procedures. The initial and basic process performed by the maintenance technician.

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c) What are some of the reasons for using a Thevenin or Norton circuit?

Answer.

Thevenin and Norton equivalent circuits are fundamental approaches a circuit to analyzing both AC and DC circuits. It is important to understand the steps involved in converting a circuit to its Thevenin or Norton equivalent, but more important still is understanding how these techniques can help you to analyze and design actual electronic devices. Thevenin's theorem states that any circuit composed of linear elements can be simplified to a signal voltage source and a single series resistance (or series impedance for AC analysis).

Norton's theorem is the same except that the voltage source and series resistance are replaced by a current source and parallel resistance.

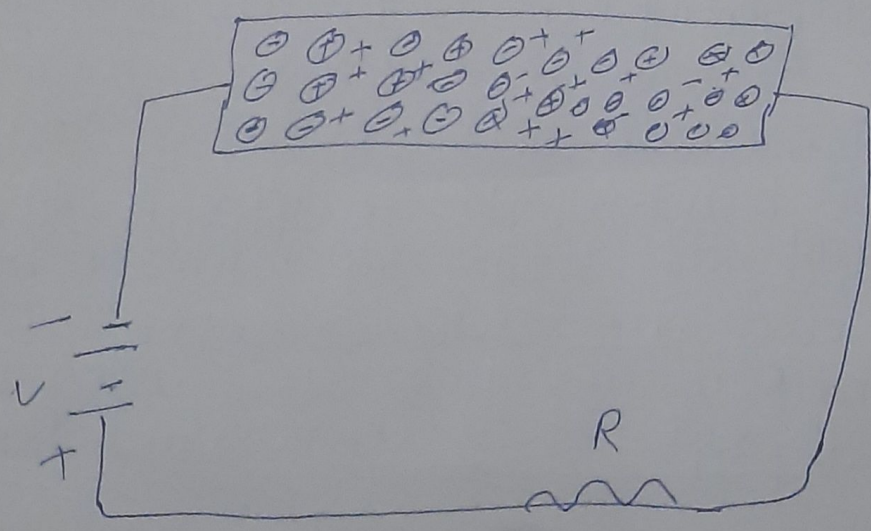
As with Thevenin's Theorem everything in the original circuit except the load resistance has been reduced to an equivalent circuit that is simpler to analyze. Also similar to Thevenin's Theorem are the steps used in Norton's Theorem to calculate the Norton source current (I_{Norton}) and Norton resistance (R_{Norton}).

Q3a: Tell me why a very small current exists in a reverse-biased diode?

Ans: When the negative battery terminal is connected to p side and the positive battery terminal is connected to n side

This connection produces reverse bias

across the diode. The following is the circuit diagram of diode in reverse bias



Q3:b: I want to know why a light emitting diode produces light. Tell me about it?

Answer:

A light-emitting diode (LED) is a semiconductor light source that emits lights when current flows through it. Electrons in the semiconductor recombine with electron holes, releasing energy in the form of photons.

(C) Do holes flow in a conductor? Why or why not? What happens to holes when they reach the end of a semiconductor?

Answer:

Name: Semiconductor "Max Fox"

Holes do exist in conductors. It's only that it's very difficult to identify them as the conduction and valance bands overlap. It should be discernible as a function of temperature or magnetic field. Electron is said to be free in the conduction band. If only the external stress (optical) electron will stay for a time dependent on material characteristics and come back to lower energy state. You can find more answer about your interest in the book of optical properties of semiconductor "Max Fox"

(D) Why is recombination important in a diode?

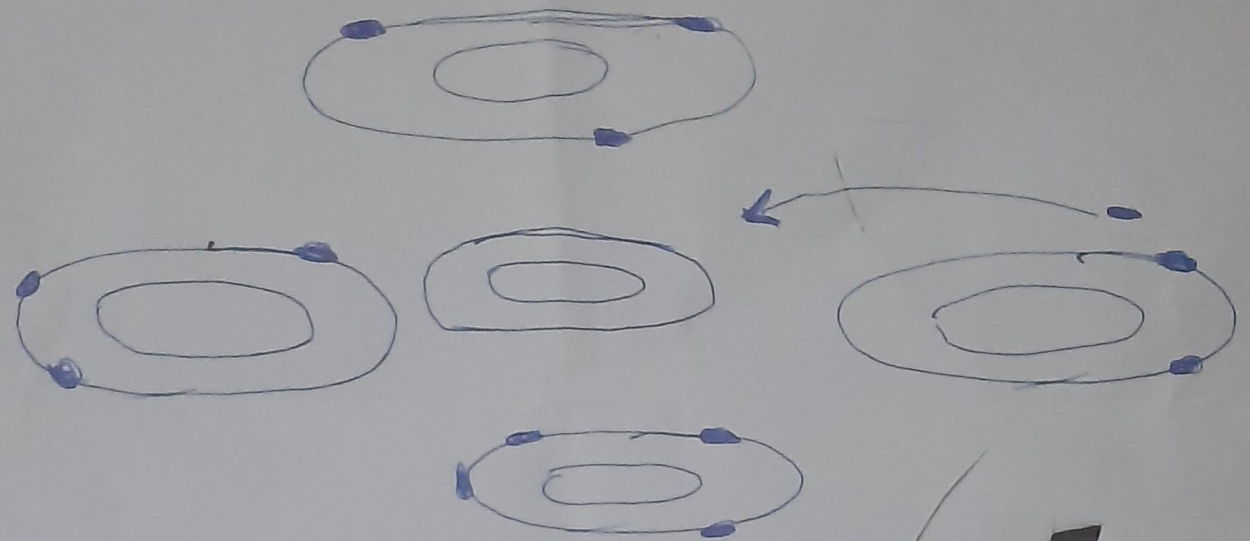
Answer:

In a pure silicon crystal, the thermal energy create an equal number of free electrons and holes. The free electronics move randomly throughout

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the crystal. Occasionally, a free electron will approach a hole, feel its attraction and fall into it. This is known as recombination. Because of the recombination energy is released.

The following is the figure showing the recombination of a free electron and a hole.



(E) What is surface leakage current?

Answer:

Defination of surface leakage current.

Diode reverse current that passes along the semiconductor materials.

